NSN 5962-01-260-3006

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View Online at https://aerobasegroup.com/nsn/5962-01-260-3006

| Body Length: |
|---|
| Between 1.180 inches and 1.220 inches |
| Body Width: |
| Between 0.564 inches and 0.596 inches |
| Body Height: |
| Between 0.060 inches and 0.095 inches |
| Maximum Power Dissipation Rating: |
| 500.0 milliwatts |
| Operating Tempurature Range: |
| -55.0/+125.0 degrees celsius |
| Storage Tempurature Range: |
| -65.0/+150.0 degrees celsius |
| Features Provided: |
| Programmable and static operation and hermetically sealed |
| Inclosure Material: |
| Ceramic |
| Inclosure Configuration: |
| Dual-in-line Dual-in-line |
| Output Logic Form: |
| Complementary-metal oxide-semiconductor logic |
| Input Circuit Pattern: |
| 12 input |
| Terminal Surface Treatment: |
| Gold |
| Voltage Rating And Type Per Characteristic: |
| 11.0 volts power source |
| Memory Device Type: |
| Rom |
| Precious Material And Location: |
| Terminal surfaces option gold |
| Precious Material: |
| Gold |
| Test Data Document: |
| 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.) |
| Terminal Type And Quantity: |
| 24 printed circuit |
| Shelf Life: |
| N/a |
| Unit Of Measure: |
| |
| Demilitarization: |

Yes - demil/mli

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